

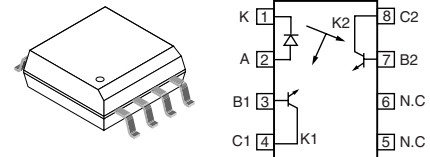
## Linear Optocoupler, PCMCIA package

### Features

- 2.3 mm High SMD package
- High sensitivity (K1) at low operating LED current
- Couples AC and DC signals
- Low input-output capacitance
- Isolation test voltage, 2130 V<sub>DC</sub>
- Low distortion, below - 80 db (typical)
- 0.4 mm internal insulation thickness
- Lead-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



RoHS  
COMPLIANT



1179085

### Agency Approvals

- CSA 93751

### Applications

- Optical DAA for V.90 FAX/Modem
- PCMCIA cards
- Digital telephone line isolation

### Description

The IL388DAA Linear Optocoupler consist of an IRLLED optically coupled to two photodiodes. The emitter is located such that both photodiodes receive approximately an equal amount of infrared light. The diodes produce a proportional amount of photocurrent. The ratio of the photocurrent stays constant with high accuracy when either the LED current or the

ambient temperature changes. Thus one can control the output diode current optically by controlling the input photodiode current.

The IL388DAA is designed to be part of the DAA2000 kit which consists of one DL207DAA, one DM207DAA, and two IL388DAAs.

The DL207DAA and DM207DAA ICs provide the drivers and receivers for the IL388DAA as well as all other telephone termination functions.

### Order Information

Part	Remarks
IL388DAA	Couples AC and DC signals, SOP-8

For additional information on the available options refer to Option Information.

### Absolute Maximum Ratings

T<sub>amb</sub> = 25 °C, unless otherwise specified

Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute Maximum Rating for extended periods of the time can adversely affect reliability.

### Input

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V <sub>R</sub>	≤ 3.0	V
Forward current		I <sub>F</sub>	≤ 30	mA
Surge current pulse width < 10 μs		I <sub>PK</sub>	≤ 150	mA
Power dissipation		P <sub>diss</sub>	≤ 150	mW
Derate linearly from 25 °C			≤ 2.0	mW/°C
Junction temperature		T <sub>j</sub>	≤ 100	°C

## Output

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		$V_R$	$\leq 15$	V
Power dissipation		$P_{diss}$	$\leq 50$	mW
Derate linearly from 25 °C			$\leq 0.65$	mW/°C
Junction temperature		$T_j$	$\leq 100$	°C

## Coupler

Parameter	Test condition	Symbol	Value	Unit
Isolation test voltage		$V_{ISO}$	$\leq 2130$	$V_{DC}$
Total package power dissipation		$P_t$	$\leq 250$	mW
Derate linearly from 25 °C			$\leq 2.8$	mW/°C
Storage temperature		$T_{stg}$	- 40 to + 150	°C
Operating temperature		$T_{amb}$	0 to + 75	°C
Lead soldering time at 260 °C			$\leq 10$	s
Isolation resistance	$V_{IO} = 500, T_{amb} = 25\text{ °C}$	$R_{IO}$	$\geq 10^{12}$	$\Omega$
	$V_{IO} = 500, T_{amb} = 100\text{ °C}$	$R_{IO}$	$\leq 10^{11}$	$\Omega$

## Electrical Characteristics

$T_{amb} = 25\text{ °C}$ , unless otherwise specified

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

## Input

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Forward voltage	$I_F = 10\text{ mA}$	$V_F$		1.8	2.1	V
Reverse current	$V_R = 3.0\text{ V}$	$I_R$		0.01	10	$\mu\text{A}$
$V_F$ temperature coefficient		$\Delta V_F / \Delta\text{ °C}$		TBD		mV/°C
Junction capacitance	$V_F = 0\text{ V}, f = 1.0\text{ MHz}$	$C_j$		15		pF
Dynamic resistance		$\Delta V_F / \Delta I_F$		6.0		$\Omega$

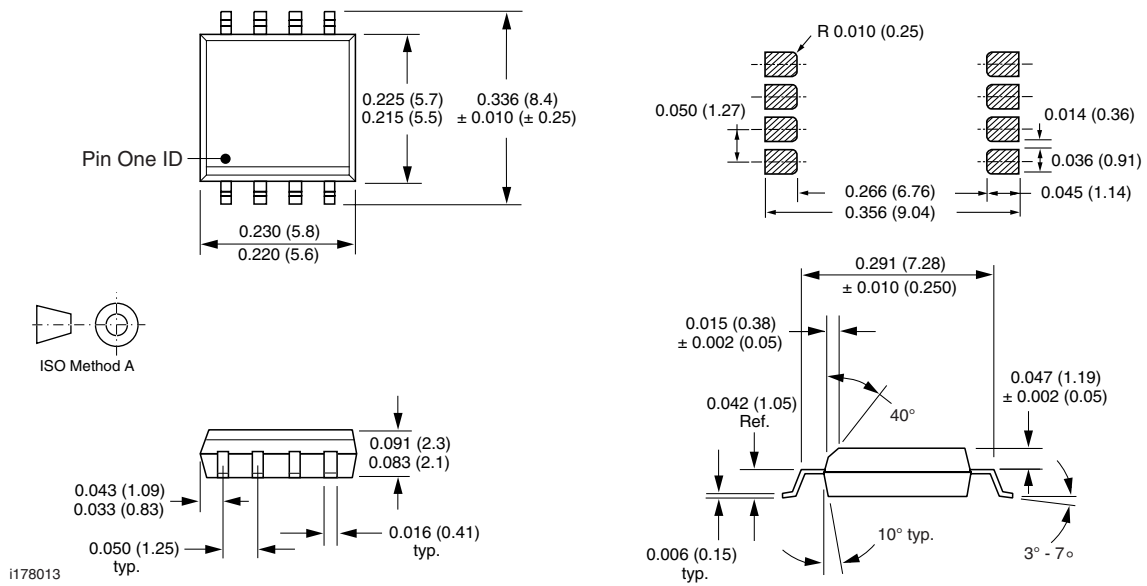
## Output

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Junction capacitance	$V_F = 0\text{ V}, f = 1.0\text{ MHz}$	$C_j$		12		pF
<b>AC Characteristics photovoltaic mode</b>						
Frequency response	$I_{P1} = 25\text{ A}$ Modulation current $\Delta I_{P1} = \pm 6.0\text{ }\mu\text{A}$	BW (-3 db)		1.0		MHz
Phase response	$I_{P1} = 25\text{ A}$ Modulation current $\Delta I_{P1} = \pm 6.0\text{ }\mu\text{A}$			45		Deg.
Rise time	$I_{P1} = 25\text{ A}$ Modulation current $\Delta I_{P1} = \pm 6.0\text{ }\mu\text{A}$	$t_r$		350		ns

## Coupler

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Capacitance (input-output)	$V_F = 0\text{ V}$ , $f = 1.0\text{ MHz}$	$C_{IO}$		1.0		pF
Common mode capacitance	$V_F = 0\text{ V}$ , $f = 1.0\text{ MHz}$	$C_{CM}$		0.5		pF
<b>Coupled characteristics</b>						
$K_1$	$I_F = 2.0\text{ mA}$ , $V_D = 0\text{ V}$	$K_1$	0.007			
THD	$f_0 = 316$ , $I_{P1} = 35\text{ }\mu\text{A}$ , $V_D = 0\text{ V}$				- 79	db
$K_3 = K_2/K_1$	$I_F = 2.0\text{ mA}$ , $V_D = 0\text{ V}$		0.70		1.30	

## Package Dimensions in Inches (mm)



### Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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